# NSN 5962-01-341-3392

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### **Overall Height:**

Between 0.245 inches and 0.430 inches

### **Body Length:**

2.435 inches

## Body Width:

Between 0.510 inches and 0.620 inches

#### **Body Height:**

Between 0.155 inches and 0.210 inches

### **Maximum Power Dissipation Rating:**

1.5 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and high impedance and w/enable and bidirectional and w/disable and w/reset

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Complementary-metal oxide-semiconductor logic

### Input Circuit Pattern:

44 input

#### **Case Outline Source And Designator:**

D-14 mil-m-38510

#### **Current Rating Per Characteristic:**

50.00 milliamperes forward current, nonrepetitive, peak total value

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Dual port sram

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Time Rating Per Chacteristic:

90.00 nanoseconds access

### Memory Device Type:

Ram

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

48 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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